

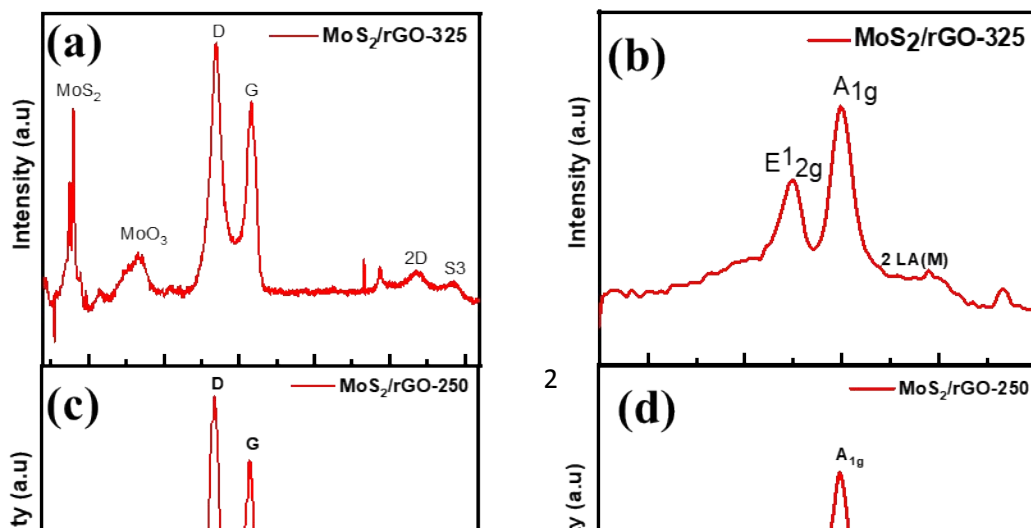
Supporting Information

Tuning Defects in the MoS₂/Reduced Graphene Oxide 2D Hybrid Materials for Optimizing Battery Performance

Kamalambika Muthukumar, Levon Leban II, Archana Sekar, Ayyappan Elangovan, Nandini
Sarkar, and Jun Li*

Department of Chemistry, Kansas State University, Manhattan, Kansas, 66506, USA.

Figure S1. The full scale and expanded region of Raman spectra of (a, b) MoS₂/rGO-325, (c, d) MoS₂/rGO-250 and (e, f) MoS₃/rGO intermediate product.



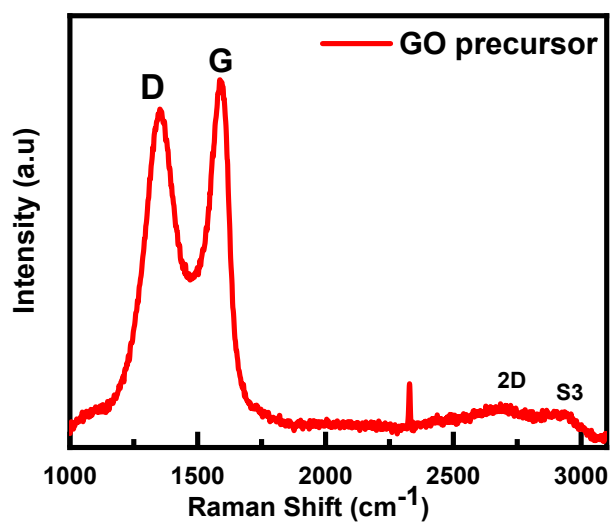


Figure S2. Raman Spectra of graphene oxide (GO) precursor material.

Figure S1. The full scale and expanded region of Raman Spectra of (a, b) MoS₂/rGO-600, (c, d) MoS₂/rGO-325 and (e, f) MoS₃/rGO intermediate product.

Table S1. Raman Analysis of GO precursor and MoS₂/rGO hybrids

Sample	I _D /I _G	I _{S3} /I _{2D}
GO Precursor	0.9	1.7
MoS ₃ /rGO-intermediate	1.3	0.3
MoS ₂ /rGO-250	1.3	0.3
MoS ₂ /rGO-325	1.3	0.4
MoS ₂ /rGO-600	1.3 3	0.4

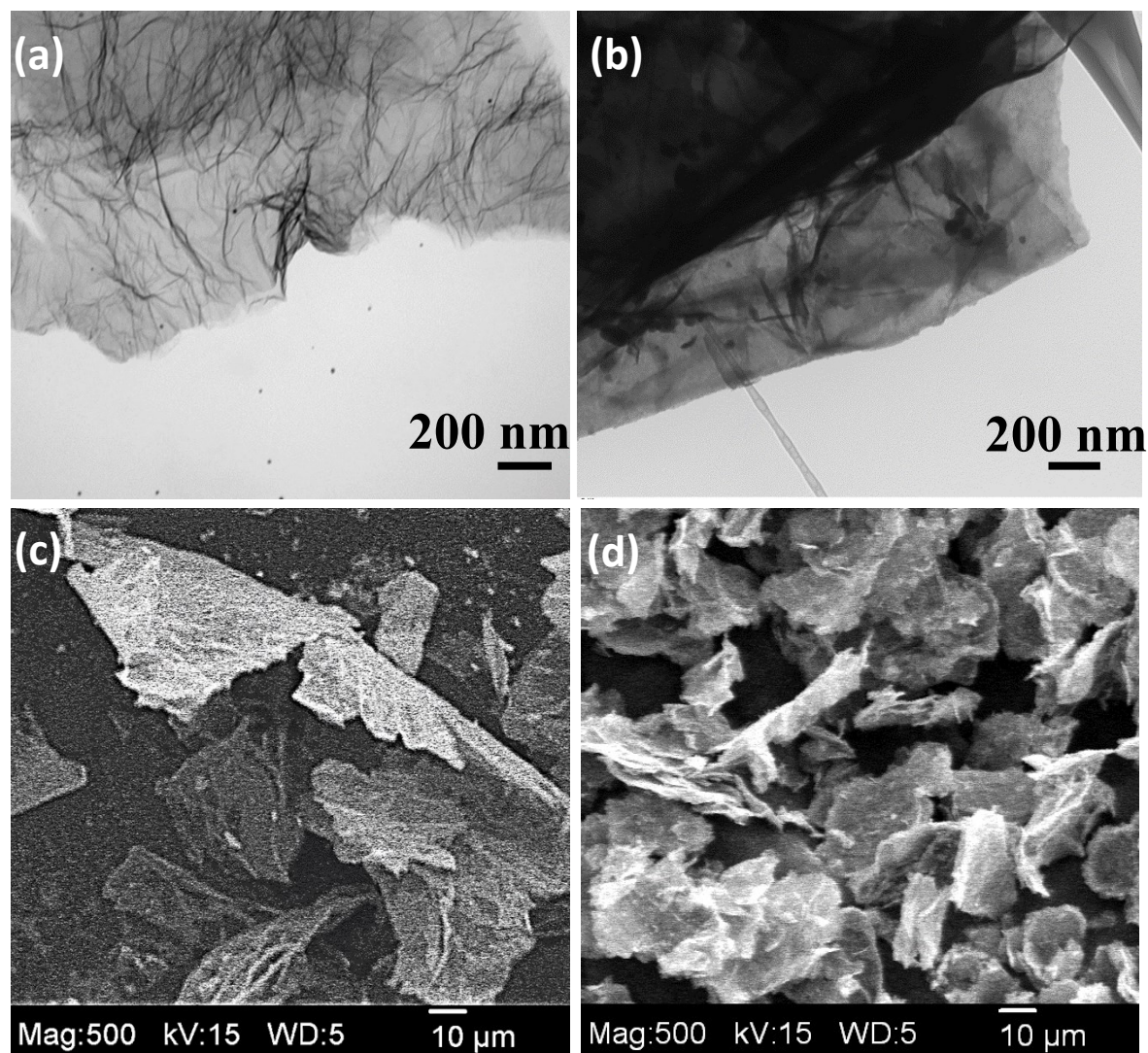


Figure S3. TEM images of (a) bare rGO nanosheets and (b) the MoS₃/rGO intermediate. (c) and (d): SEM images of these two samples, respectively. The bare rGO sample was prepared with microwave irradiation in absence of ATM precursors before subjected to thermal annealing at 600 °C in 3% H₂ and 97% Ar. The MoS₃/rGO intermediate was obtained after the microwave irradiation in presence of ATM precursors but was not subjected to the thermal annealing.

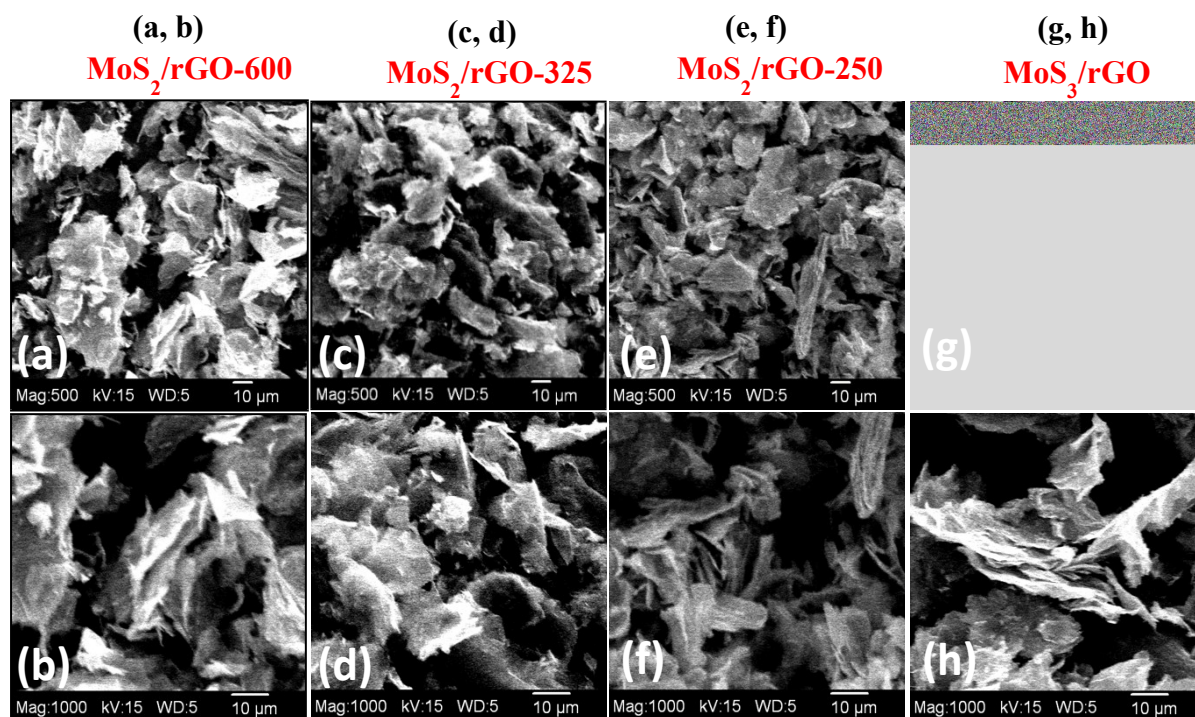


Figure S4. Low- and higher-magnification FESEM images of (a, b) MoS₂/rGO-600, (c, d) MoS₂/rGO-325, (e, f) MoS₂/rGO-250, and (g, h) MoS₃/rGO-intermediate.

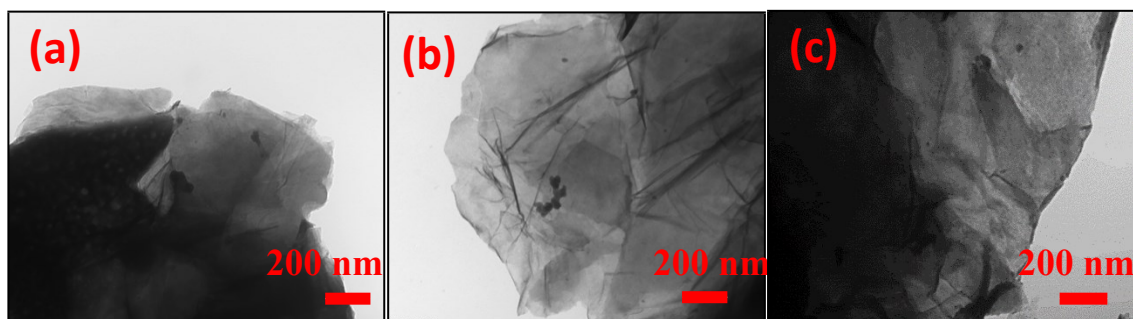


Figure S5. TEM images of (a) MoS₂/rGO-250, (b) MoS₂/rGO-325, and (c) MoS₂/rGO-600.

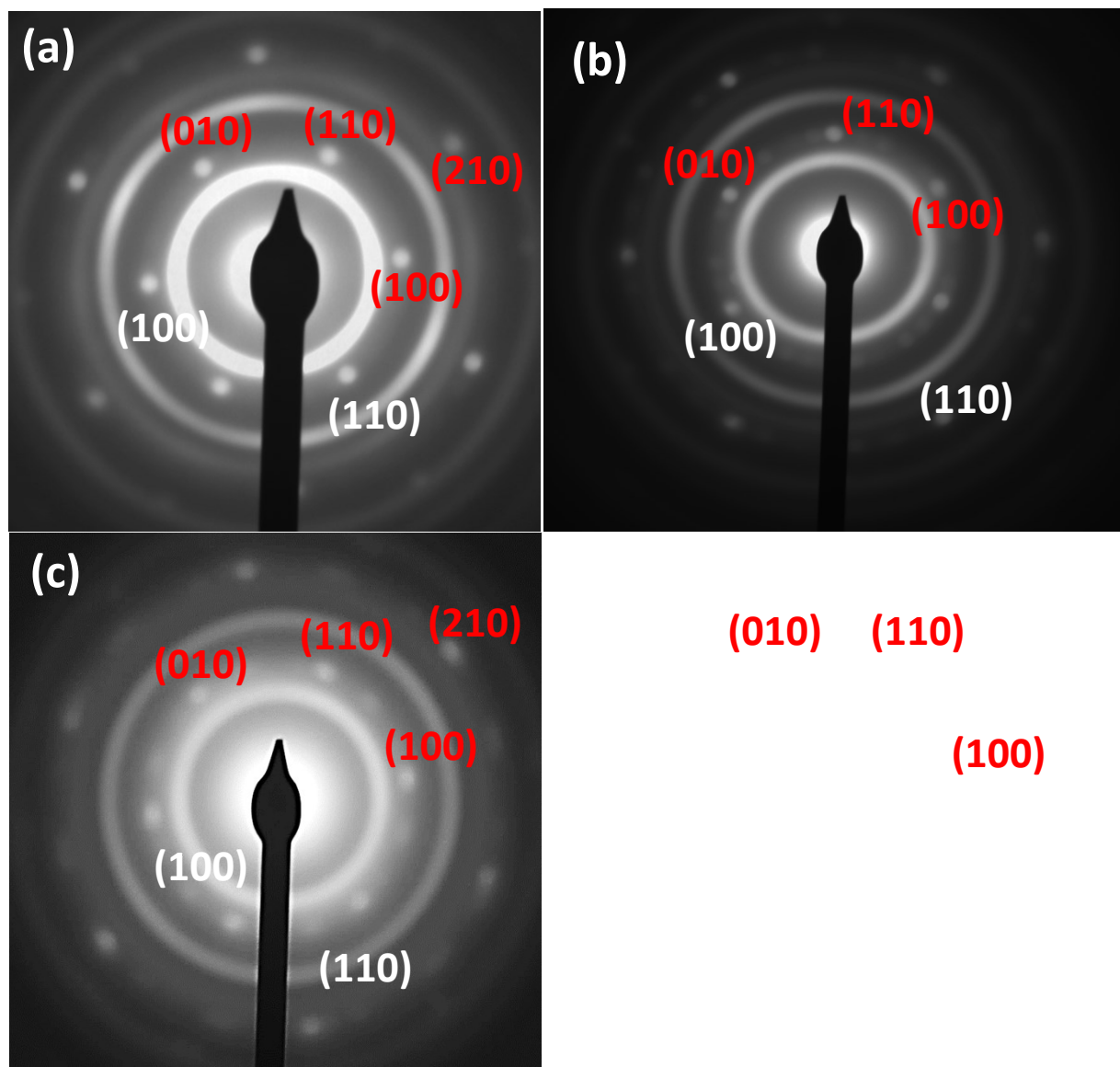
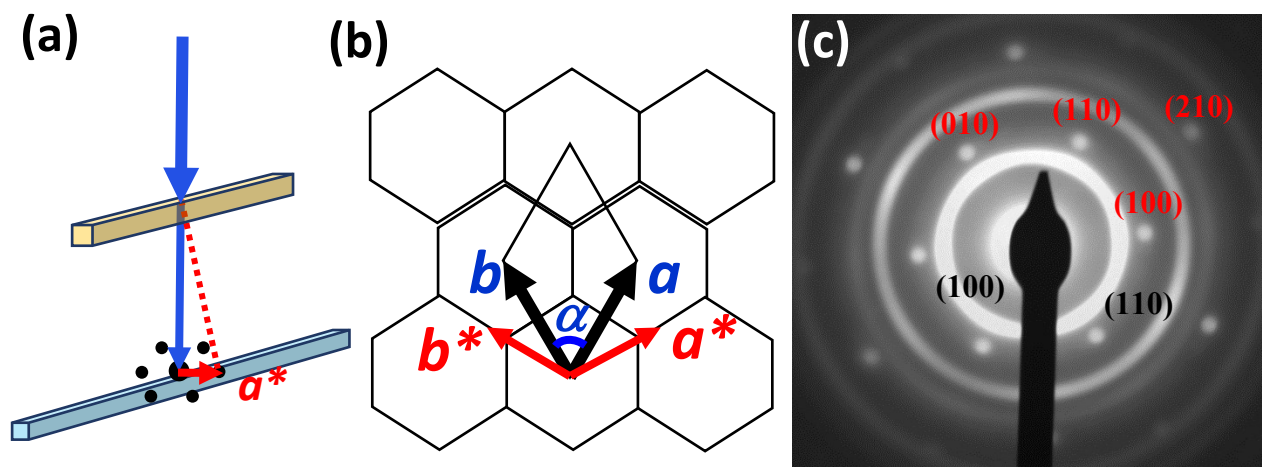


Figure S6. SAED patterns of (a) MoS₂/rGO-600, (b) MoS₂/rGO-325, (c) MoS₂/rGO-250, and (d) MoS₃/rGO intermediate. The red-colored indices at the top indicate the isolated 2D electron diffraction spots with the six-fold symmetry from the rGO nanosheets, while the white indices at the bottom indicate the continuous rings of 2D powder electron diffraction from MoS₂ nanopatches with random rotational orientations in the rGO plane.



(d)

- **For 2D crystals with a hexagonal lattice:**
 $a = b, \alpha = 60^\circ$
 a - real space lattice; a^* - reciprocal space lattice
 $a \cdot a^* = 2\pi$ i.e. $a \times a^* \times \cos 30^\circ = 2\pi$
 $a^* = 2\pi / (a \times \cos 30^\circ)$ or $a = 2\pi / (a^* \times \cos 30^\circ)$
- **For isolated SAED spots from rGO:**
rGO: $a = 2.46 \text{ \AA} \Rightarrow a^* = 2.948 \text{ \AA}^{-1}$
- **Use a^* of rGO to calibrate the a^* of the continuous rings from MoS_2 :**
(100) ring of MoS_2 : $a^* = 2.29 \text{ \AA}^{-1} \Rightarrow a = 3.17 \text{ \AA}$

Figure S7. (a) Schematic illustration of the SAED with the electron beam perpendicular to the 2D crystal plane. (b) The relationship of the real space 2D hexagonal lattice a and b and the reciprocal diffraction lattice (a^* and b^*). (c) The SAED pattern of $\text{MoS}_2/\text{rGO-600}$. (d) The procedure to derive the MoS_2 lattice in reference to the sharp hexagonal SAED pattern of the 2D monocrystalline rGO nanosheets.

Table S2. The parameters derived from deconvolution of Mo 3d and S 2p XPS spectra.

		MoS ₃ /rGO intermediate		MoS ₂ /rGO-250		MoS ₂ /rGO-325		MoS ₂ /rGO-600	
		B.E. (eV)	Atomic % in the same element	B.E. (eV)	Atomic % in the same element	B.E. (eV)	Atomic % in the same element	B.E. (eV)	Atomic % in the same element
Mo ⁴⁺	3d _{5/2}	229.08	28.58	229.03	83.08	229.12	66.41	229.28	68.24
	3d _{3/2}	232.21		232.16		232.25		232.41	
Mo ⁵⁺	3d _{5/2}	229.32	19.39	230.52	9.44	Mo ⁵⁺ is not present in this sample		Mo ⁵⁺ is not present in this sample	
	3d _{3/2}	232.45		233.65					
Mo ⁶⁺	3d _{5/2}	232.11	52.03	232.68	7.48	231.90	33.58	232.18	31.75
	3d _{3/2}	235.24		235.81		235.03		235.31	
S ²⁻	2p _{3/2}	162.59	45.99	161.68	46.46	161.93	86.50	162.09	100
	2p _{1/2}	163.78		162.47		163.21		163.27	
S ₂ ²⁻	2p _{3/2}	164.76	54.01	162.94	53.54	163.41	13.50		
	2p _{1/2}	165.79		164.10		164.58			
Mo : S		1:2.4		1:2.9		1:2.3		1:1.9	

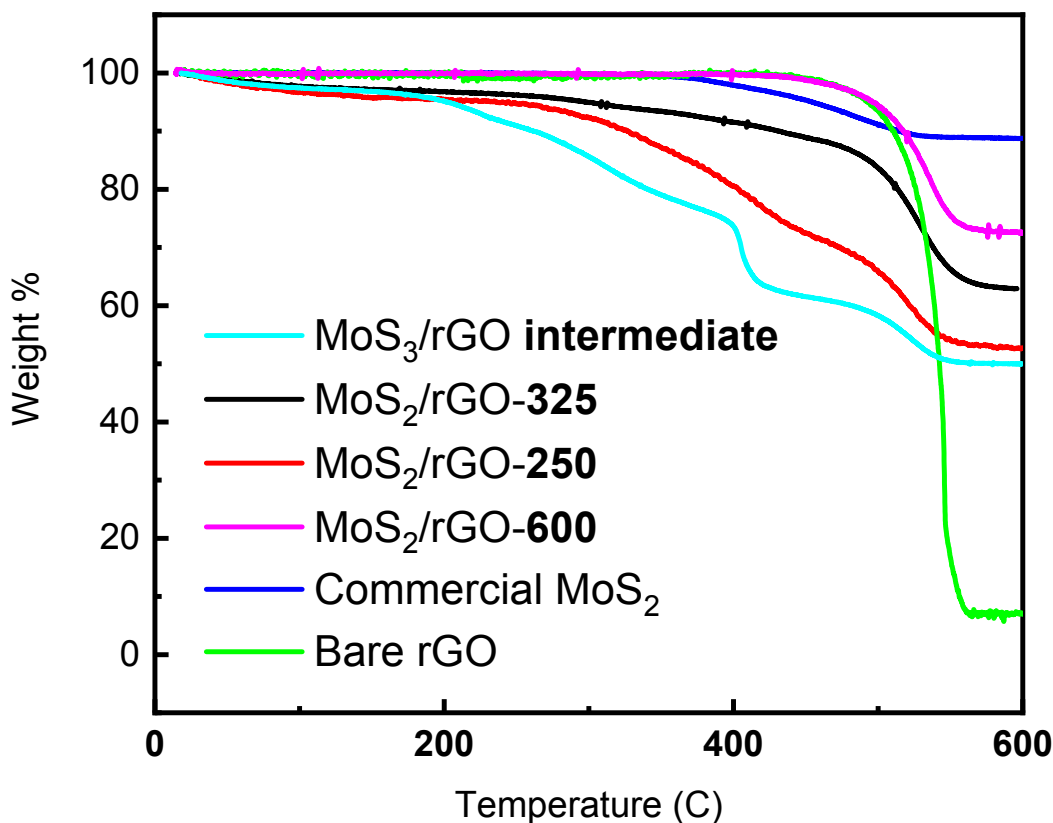


Figure S8. Thermogravimetric analyses of various hybrid materials and control samples (commercial MoS_2 powder and bare rGO synthesized at the same conditions as $\text{MoS}_2/\text{rGO-600}$ but without presence of ATM precursors).

Determination of weight % of MoS_2 in $\text{MoS}_2/\text{rGO-600}$:

1. Bulk MoS_2 shows gradual weight loss of 10.1% from 370 °C to 600°C due to the conversion of MoS_2 to MoO_3 .
2. Control rGO shows a steep weight loss of 93.36% at 420 °C due to the conversion of rGO to graphitic carbon.
3. Based on the above-mentioned weight loss of control samples
4. Weight loss from 370 °C till 600 °C = Weight loss of MoS_2 + Weight loss of rGO

$$= (\text{Weight\% of } \text{MoS}_2) * 10.1\% + (1 - \text{Weight\% of } \text{MoS}_2) * 93.36\%$$
5. Weight% of rGO = $1 - \text{Weight\% of } \text{MoS}_2$
6. $(99.91\% - 72.57\%) = (\text{Weight \% of } \text{MoS}_2) * 10.1\% + (1 - \text{Weight \% of } \text{MoS}_2) * 93.36\%$
7. Weight % of MoS_2 in $\text{MoS}_2/\text{rGO-600}$ = 79.29%

Table S3: Elemental Analysis of MoS_x/rGO samples

Samples	wt% of N	wt% of C	wt% of H	wt% of O	wt% of S	wt% of Mo ^a	wt% of MoS _x ^b	wt% of rGO ^c	at% of Mo ^d	at% of S ^d	Mo:S ^e
MoS ₂ /rGO-600	0.30	19.98	0.15	1.17	33.52	44.88	78.40	21.15	13.51	30.69	1:2.3
MoS ₂ /rGO-325	0.62	22.46	0.31	4.62	31.17	40.82	71.99	27.08	9.58	21.60	1:2.3
MoS ₂ /rGO-250	1.07	18.62	0.31	5.14	38.56	36.30	74.86	23.76	9.90	31.25	1:3.2
MoS ₃ /rGO-intermediate	1.82	20.31	0.99	11.07	35.38	30.43	65.81	31.38	6.50	22.36	1:3.4

Note:

Elements: N - Nitrogen; C - Carbon; H - Hydrogen; O - Oxygen; S - Sulfur; Mo - Molybdenum.

^a Weight percentage of Mo = 100 % - (wt% of C + wt% of N + wt% of H + wt% of O + wt% of S)

^b Weight percentage of MoS_x = wt% of Mo + wt% of S

^c Weight percentage of rGO = wt% of C + wt% of O

$$^d \text{ at\% of } x = \frac{\text{wt\% of } x / \text{AW of } X}{\sum_{i=1}^n (\text{wt\% of } i / \text{AW of } i)}, \text{ AW} = \text{atomic weight}$$

$$^e \text{ Atomic ratio of Mo:S} = \frac{\text{at\% of Mo}}{\text{at\% of S}}$$

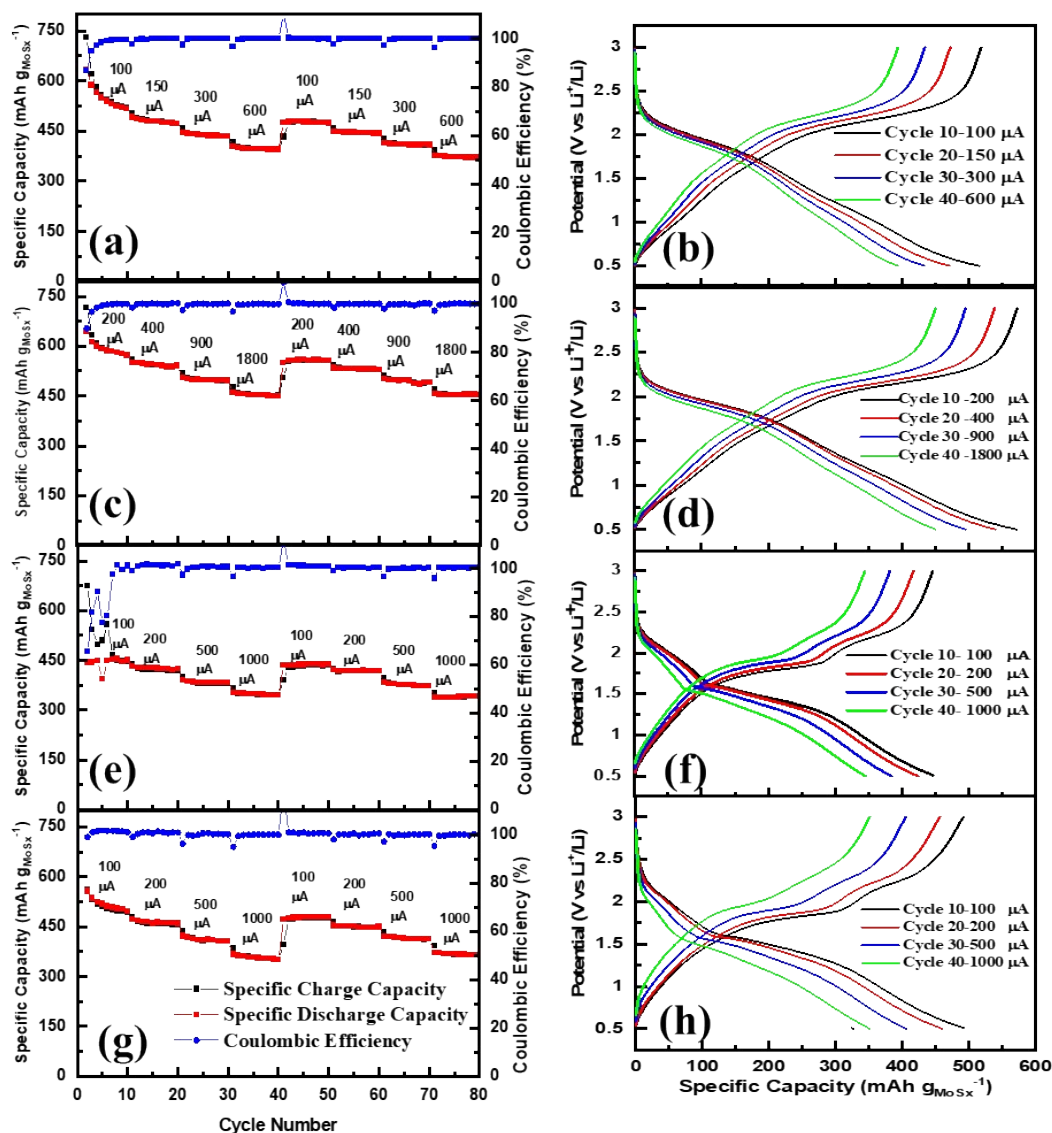


Figure S9. Rate Performance at varied current rates and representative galvanostatic charge/discharge curves of Li-ion half cells with the cathode made of (a, b) MoS₂/rGO-600 (0.88 mg), (c, d) MoS₂/rGO-325 (1.44 mg), (e, f) MoS₂/rGO-250 (0.82 mg) and (g, h) MoS₃/rGO intermediate material (1.76 mg). Panels (a), (c) and (e) have the same legend as panel (g).

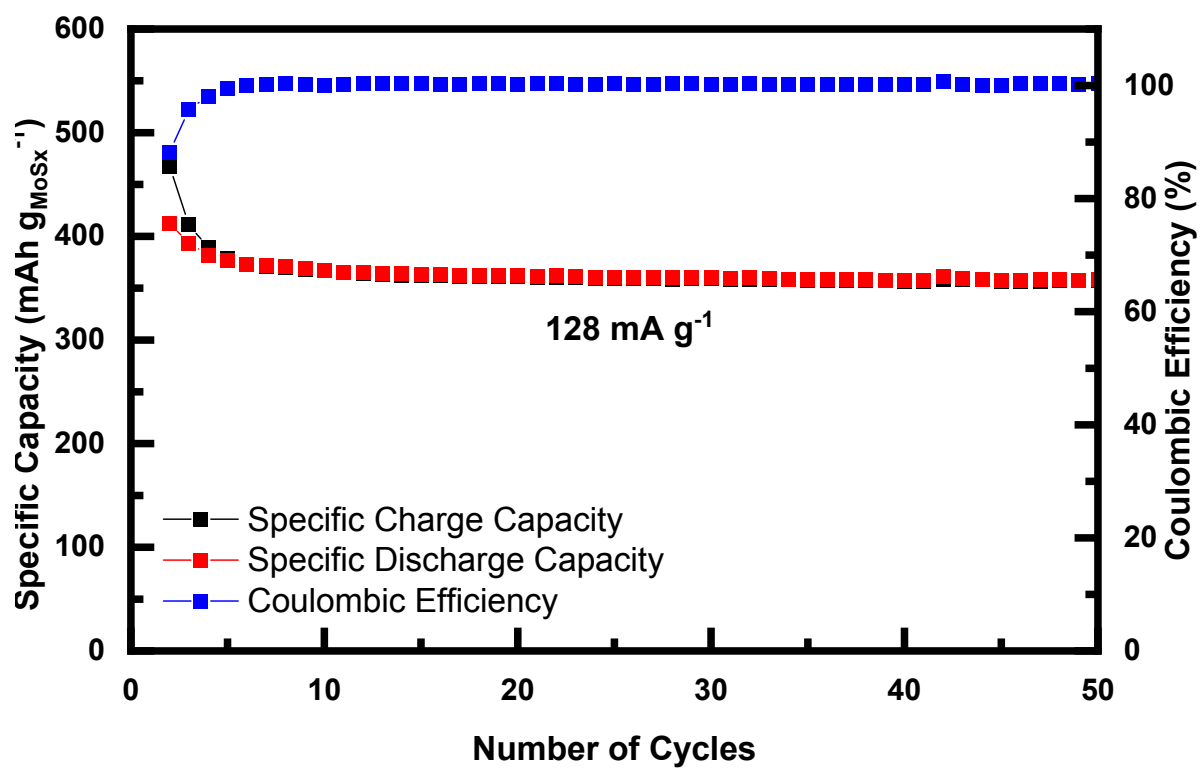


Figure S 10. Long term stability test of Li ion half cells with anode made of MoS₂/rGO-600.

Calculation of the Coulombic efficiency of battery tests:

$$\text{Coulombic Efficiency of MoS}_x \text{ in LIB} = \frac{\text{Specific Discharge Capacity}}{\text{Specific Charge Capacity}} * 100 \rightarrow (1)$$

Calculation of the specific capacity of MoS_x/rGO samples in battery tests:

$$\text{Specific capacity of MoS}_x = \frac{\text{measured capacity}}{\text{Total Mass of hybrid } x \text{ (wt\% of MoS}_x\text{)}} \rightarrow (2)$$

Discussion on rGO contribution to the Li-ion storage capacity:

The small contribution from rGO can be deducted from the specific capacity. As shown in Table S3, the stabilized specific capacity at 100 μA charge/discharge current is about 73, 86, 111 and 53 $\text{mAh g}_{\text{rGO}}^{-1}$ for the corresponding control samples rGO-600, rGO-325, rGO-250 and rGO-intermediate. After deducting these contributions based on the wt% of rGO by equations below Table S3, the specific capacity attributed to MoS_x is adjusted to 499, 540, 411 and 467 $\text{mAh g}_{\text{MoS}_x}^{-1}$ for MoS₂/rGO-600, MoS₂/rGO-325, MoS₂/rGO-250 and MoS₃/rGO-intermediate, respectively. The contribution by rGO is only 3.9%, 5.7%, 8.0% and 5.1% in MoS₂/rGO-600, MoS₂/rGO-325, MoS₂/rGO-250 and MoS₃/rGO-intermediate, respectively. These small corrections are insignificant to the conclusions in the main manuscript.

Table S4.

Sample	Specific Capacity of MoS _x (mAh/g _{MoS_x}) ^a	Specific Capacity of rGO (mAh/g _{rGO}) ^b	(wt% of rGO / wt% of MoS _x) ^c	Corrected Specific Capacity ^d (mAh/g _{MoS_x})	Relative Contribution of rGO ^e
MoS ₂ /rGO-600	519	73	0.27	499	3.9
MoS ₂ /rGO-325	573	86	0.38	540	5.7
MoS ₂ /rGO-250	446	111	0.32	411	8.0
MoS ₃ /rGO-intermediate	492	53	0.48	467	5.1

Estimation of contribution to

the specific capacity by rGO and MoS_x in LIB

Note:

^a Based on the 10th cycle at 100 mA in Figure S8.

^b Based on the 10th cycle at 100 mA in Figure S10.

^c Based on the values from Table S2.

^d Corrected specific capacity = (Specific capacity of MoS_x) - [(Specific capacity of rGO) * ($\frac{\text{wt\% of rGO}}{\text{wt\% of MoS}_x}$)]

^e Relative contribution of rGO = $\frac{\text{Specific Capacity of MoS}_x - \text{Corrected Specific capacity}}{\text{Specific Capacity of MoS}_x} * 100$

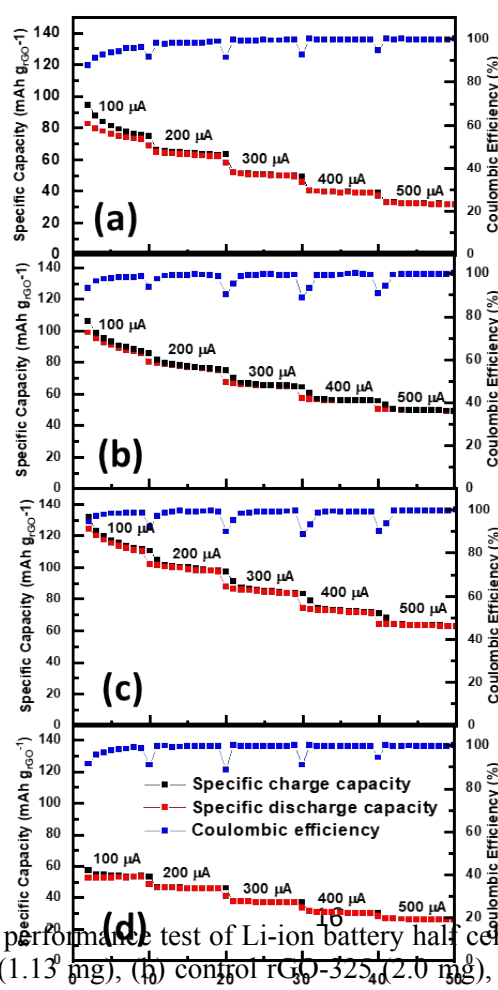


Figure S11. Rate performance test of Li-ion battery half cells with the cathode made of (a) control rGO-600 (1.13 mg), (b) control rGO-325 (2.0 mg), (c) control rGO-250 (1.03 mg) and (d) control rGO-intermediate (1.25 mg). Panels (a), (b) and (c) follow the same legend as panel (d).

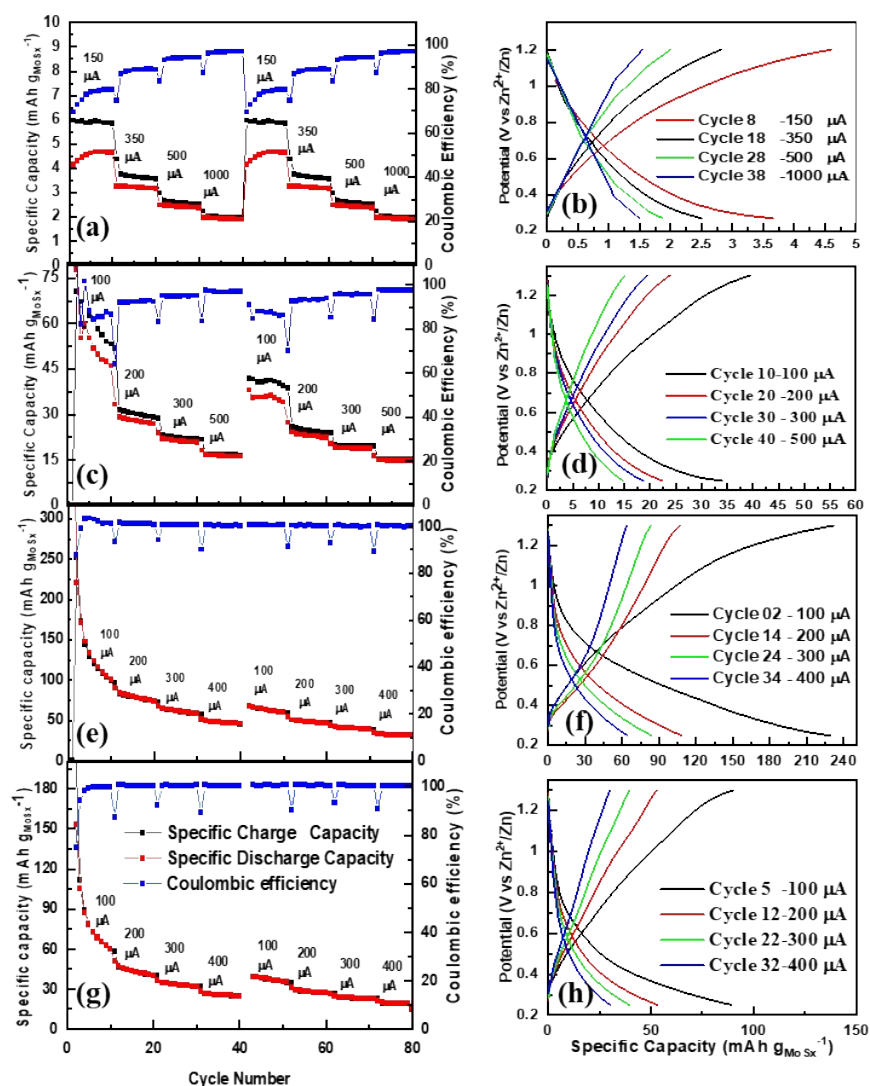


Figure S12. Galvanostatic charge-discharge curves and the rate performance of Zn-ion battery half-cells with the cathode made of (a, b) MoS₂/rGO-600 (0.87 mg), (c, d) MoS₂/rGO-325 (1.36 mg), (e, f) MoS₂/rGO-250 (1.28 mg), and (g, h) MoS₃/rGO intermediate hybrid material (0.88 mg). Panels (a), (c) and (e) follow same legend as panel (g).

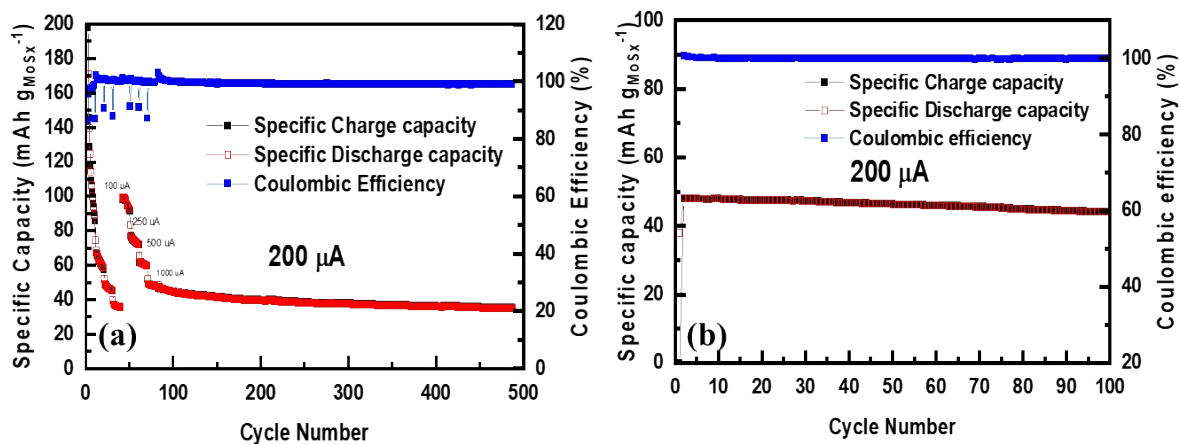


Figure S13. The cycle stability test of Zn-ion battery half-cells with the cathode made of (a) MoS₂/rGO-250 (2.16 mg) and (b) the MoS₃/rGO intermediate material (0.88 mg). The charge/discharge was carried out at 0.25 – 1.30 V vs. Zn²⁺/Zn.

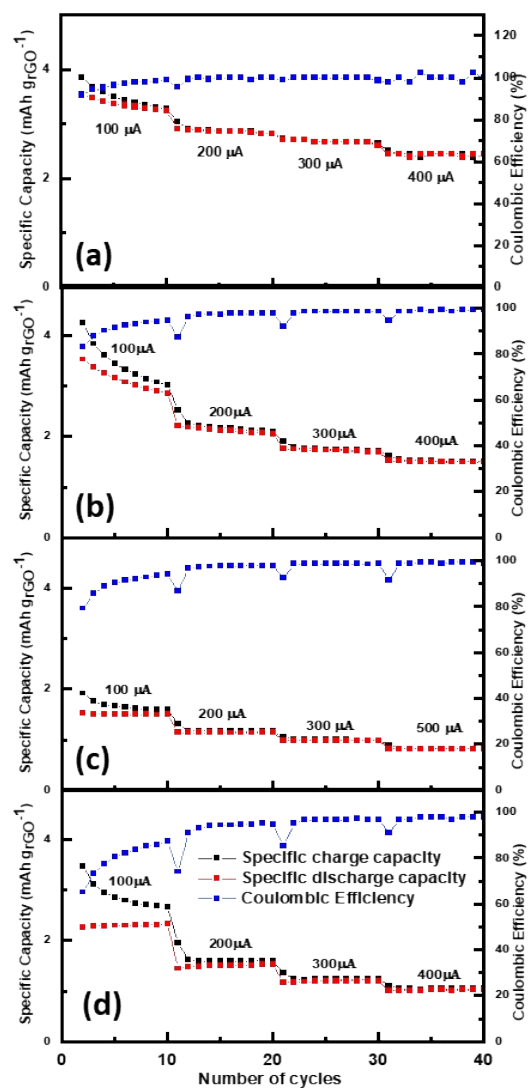


Figure S14. Rate performance test of Zn ion battery half cells with the cathode made of (a) control rGO-600 (1.38 mg) (b) control rGO-325 (2.0 mg) (c) control sample-250 (0.90 mg) (d) control rGO-intermediate (1.50 mg). Panels (a), (b) and (c) follow same legend as panel (d).